

2SK848

T-39-05



2062

N-Channel MOS Silicon FET

Very High-Speed Switching Applications

©2842

Features

- Low ON resistance, very high-speed switching

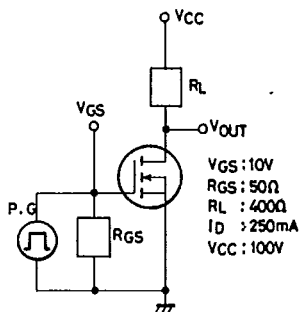
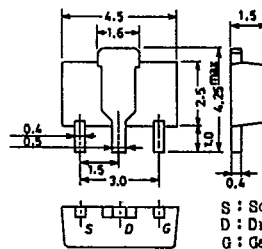
Absolute Maximum Ratings at Ta = 25°C

		unit
Drain to Source Voltage	V _{DS}	250 V
Gate to Source Voltage	V _{GS}	±20 V
Drain Current (DC)	I _D	500 mA
Drain Current (Pulse)	I _{D peak}	1 A
Maximum Power Dissipation	P _D Mounted on ceramic PCB (250mm ² × 0.8mm)	1.5 W
	P _D Tc = 25°C	3.5 W
Junction Temperature	T _j	150 °C
Storage Temperature	T _{stg}	-55 to +150 °C

Electrical Characteristics at Ta = 25°C

		min	typ	max	unit
Drain to Source Breakdown Voltage	V _{DSS} I _D = 1mA, V _{GS} = 0	250			V
Drain to Source Cutoff Current	I _{DSS} V _{DS} = 250V, V _{GS} = 0			100	μA
Gate to Source Leakage Current	I _{GSS} V _{GS} = ±20V, V _{DS} = 0			±100	nA
Gate to Source Cutoff Voltage	V _{GS(off)} V _{DS} = 10V, I _D = 1mA	0.8		2.5	V
Forward Transfer Admittance	y _{fs} V _{DS} = 10V, I _D = 250mA	100	250		mS
Saturation Resistance	R _{DS(on)} I _D = 250mA, V _{GS} = 10V		6	9	Ω
Input Capacitance	C _{iss} V _{DS} = 20V, f = 1MHz		60		pF
Output Capacitance	C _{oss} V _{DS} = 20V, f = 1MHz		20		pF
Reverse Transfer Capacitance	C _{rss} V _{DS} = 20V, f = 1MHz		4		pF
Turn-ON Time	t _{on} I _D = 250mA, V _{GS} = 10V		25		ns
Turn-OFF Time	t _{off} I _D = 250mA, V _{GS} = 10V		60		ns

(Note) Be careful in handling the 2SK848 because it has no protection diode between gate and source.

Switching Time Test Circuit**Case Outline 2062**
(unit: mm)

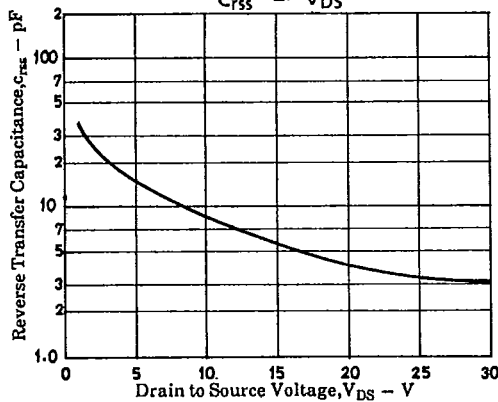
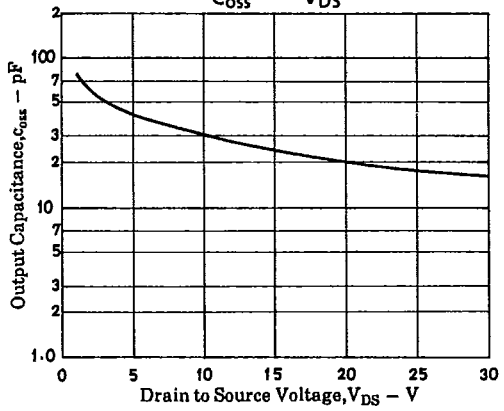
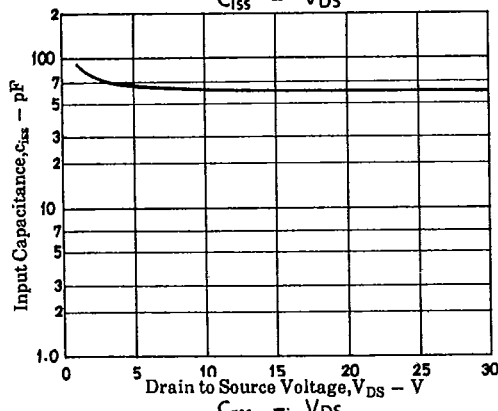
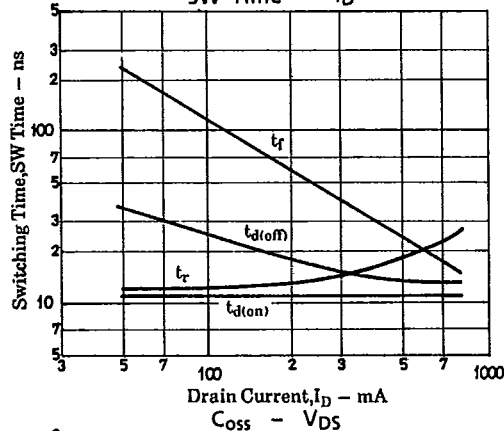
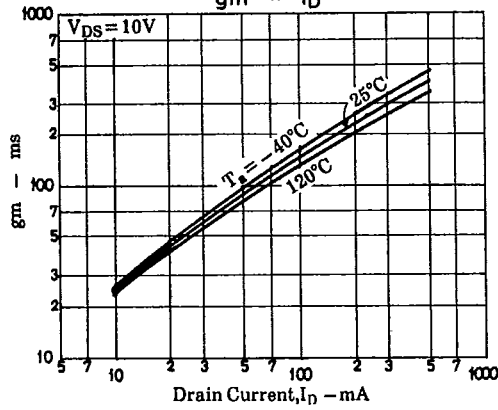
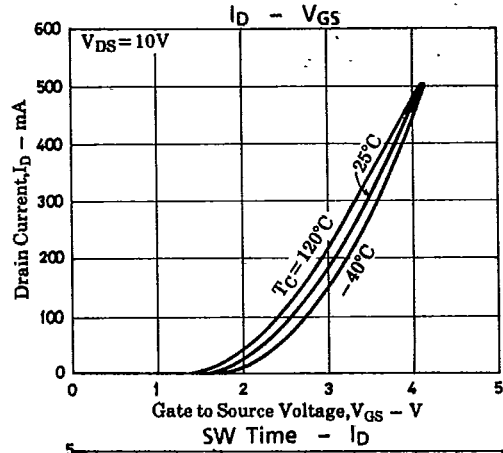
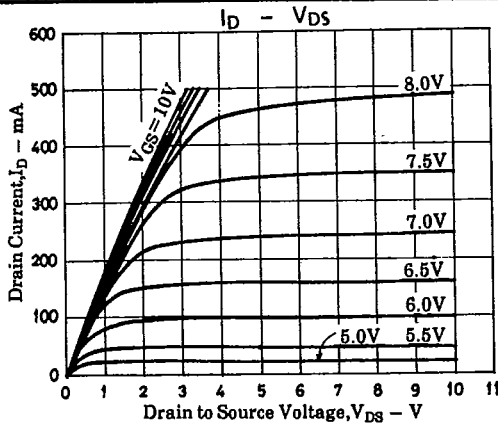
S : Source
D : Drain
G : Gate
SANYO : PCP

N288MO,TS No.2842-1/2

395

2SK848

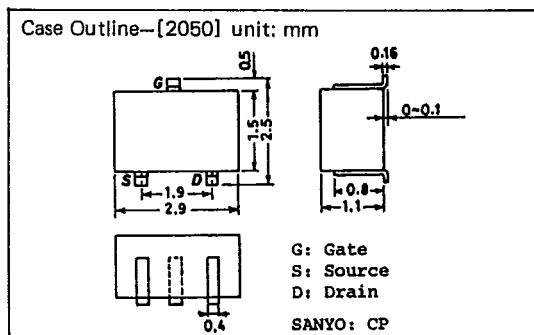
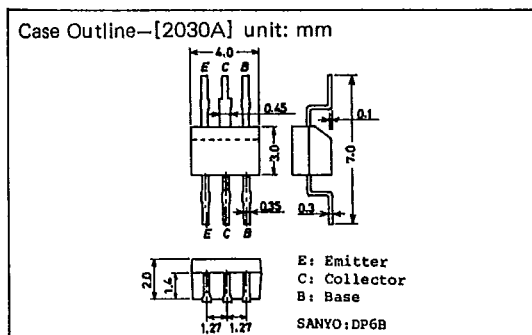
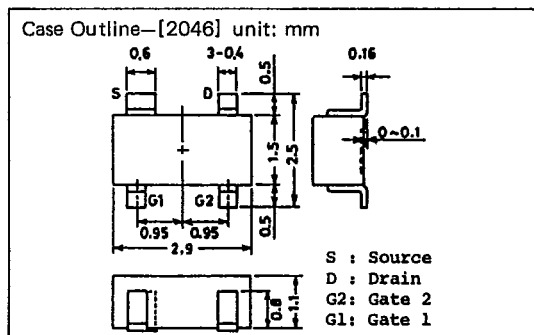
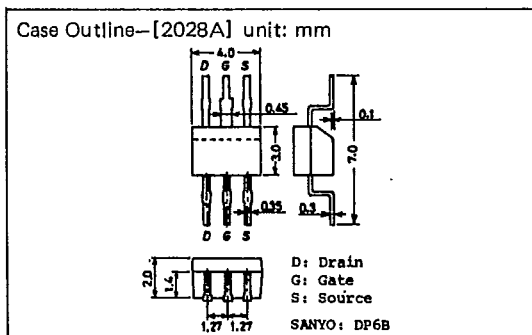
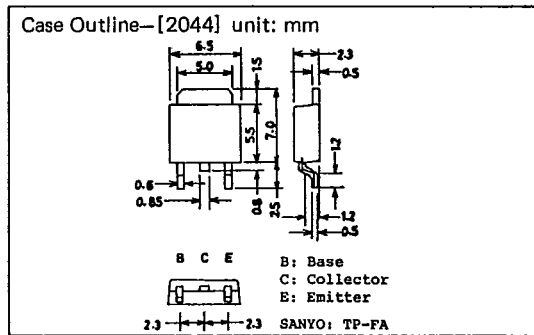
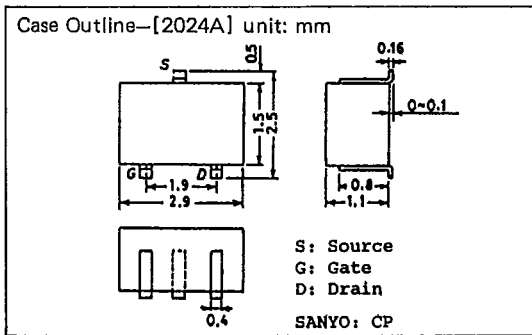
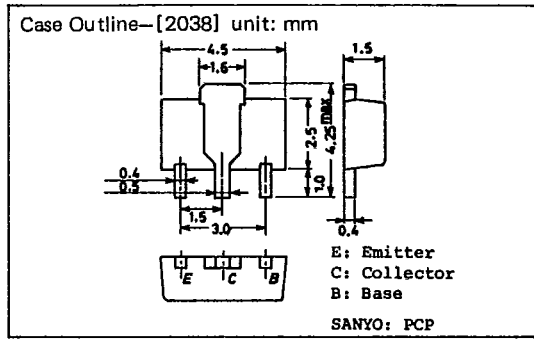
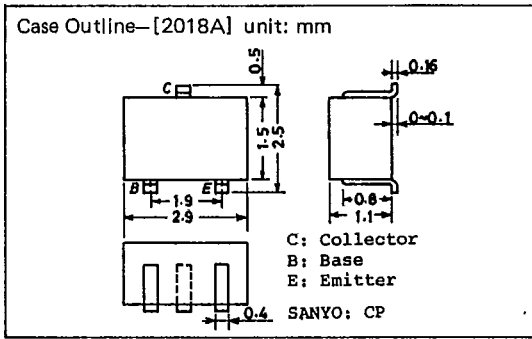
T-39-05



T-91-20

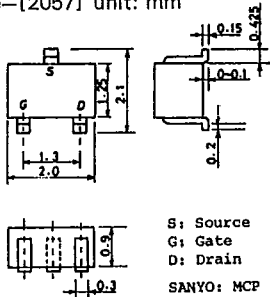
CASE OUTLINES OF SURFACE MOUNT TRANSISTORS

- All of Sanyo surface mount transistor case outlines are illustrated below.
- All dimensions are in mm, and dimensions which are not followed by min. or max. are represented by typical values.
- No marking is indicated.



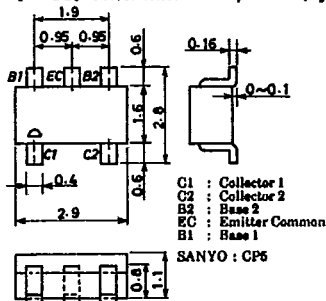
T-91-20

Case Outline—[2057] unit: mm



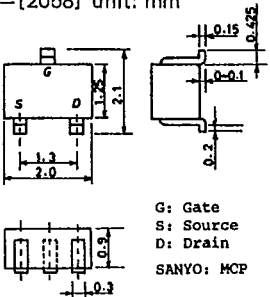
S: Source
G: Gate
D: Drain
SANYO: MCP

Case Outline—[2066] unit: mm



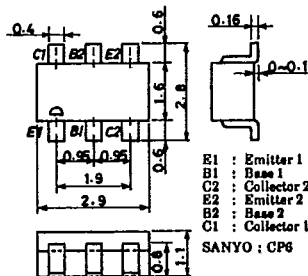
C1 : Collector 1
C2 : Collector 2
B2 : Base 2
EC : Emitter Common
B1 : Base 1
SANYO : CP6

Case Outline—[2058] unit: mm



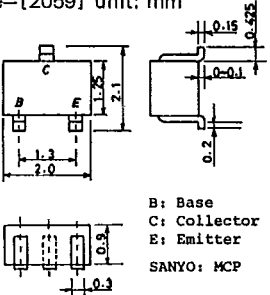
G: Gate
S: Source
D: Drain
SANYO: MCP

Case Outline—[2067] unit: mm



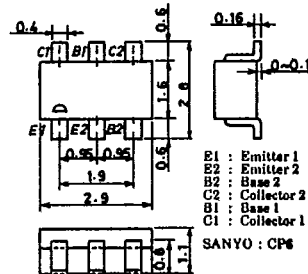
E1 : Emitter 1
B1 : Base 1
C2 : Collector 2
E2 : Emitter 2
B2 : Base 2
C1 : Collector 1
SANYO : CP6

Case Outline—[2059] unit: mm



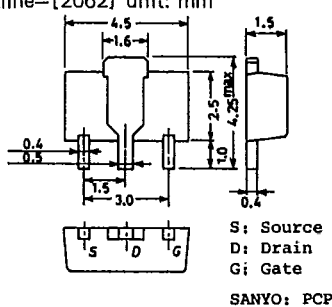
B: Base
C: Collector
E: Emitter
SANYO: MCP

Case Outline—[2068] unit: mm



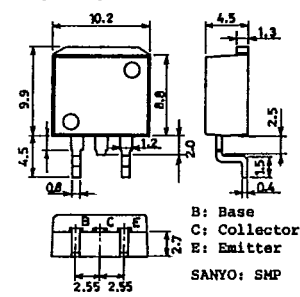
B1 : Emitter 1
E2 : Emitter 2
B2 : Base 2
C2 : Collector 2
B1 : Base 1
C1 : Collector 1
SANYO : CP6

Case Outline—[2062] unit: mm



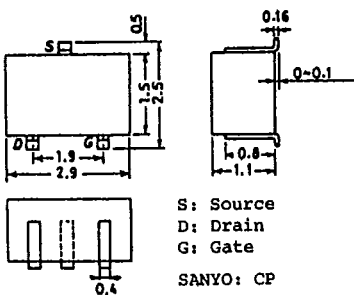
S: Source
D: Drain
G: Gate
SANYO: PCP

Case Outline—[2069] unit: mm



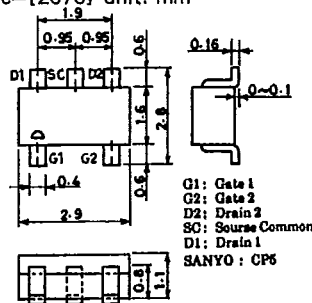
B: Base
C: Collector
E: Emitter
SANYO: SMP

Case Outline—[2065] unit: mm



S: Source
D: Drain
G: Gate
SANYO: CP

Case Outline—[2070] unit: mm



G1 : Gate 1
G2 : Gate 2
D2 : Drain 2
SC : Source Common
D1 : Drain 1
SANYO : CP6

T-9120

